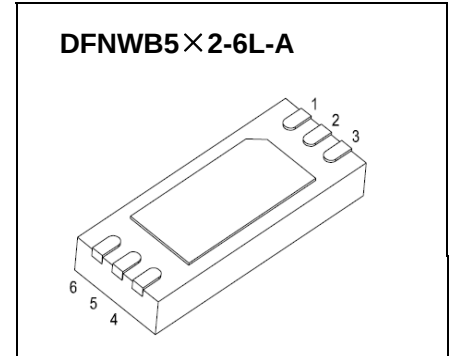


DFNWB5×2-6L-A Plastic-Encapsulate MOSFETS

CJND8804 Dual N-Channel MOSFET

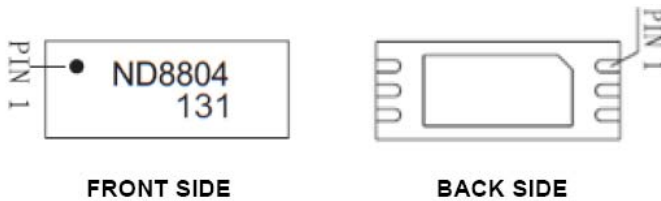
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
20V	13mΩ@10V	8A
	14mΩ@4.5V	
	15.5mΩ@3.8V	
	19mΩ@2.5V	
	27mΩ@1.8V	



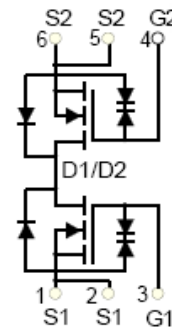
DESCRIPTION

The CJND8804 uses advanced trench technology to provide excellent $R_{DS(on)}$ and low gate charge. It is ESD protected. This device is suitable for use as a uni-directional or bi-directional load switch, facilitated by its common-drain configuration.

MARKING:



Equivalent Circuit



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	8	A
Pulsed Drain Current	I_{DM}^*	30	A
Thermal Resistance from Junction to Ambient(note1)	$R_{\theta JA}$	175	$^{\circ}\text{C/W}$
Thermal Resistance from Junction to Ambient(note2)		70	$^{\circ}\text{C/W}$
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55~+150	$^{\circ}\text{C}$
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	T_L	260	$^{\circ}\text{C}$

*Repetitive rating: Pluse width limited by junction temperature.

Note: 1.When mounted on a minimum pad.

2.When mounted on 1 in² of 2oz copper board.

MOSFET ELECTRICAL CHARACTERISTICS

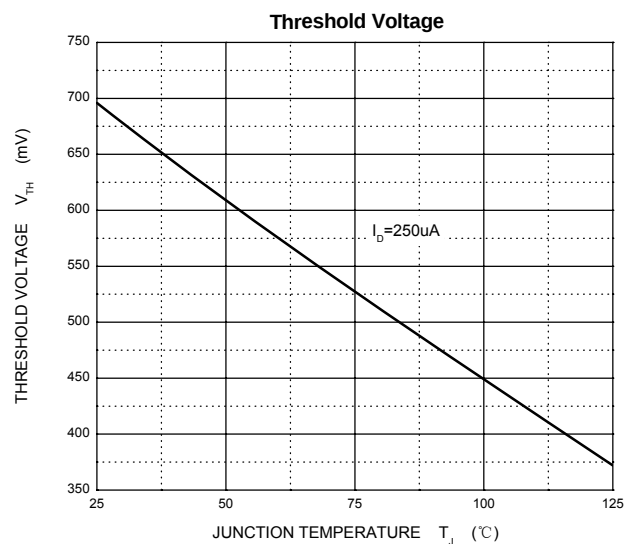
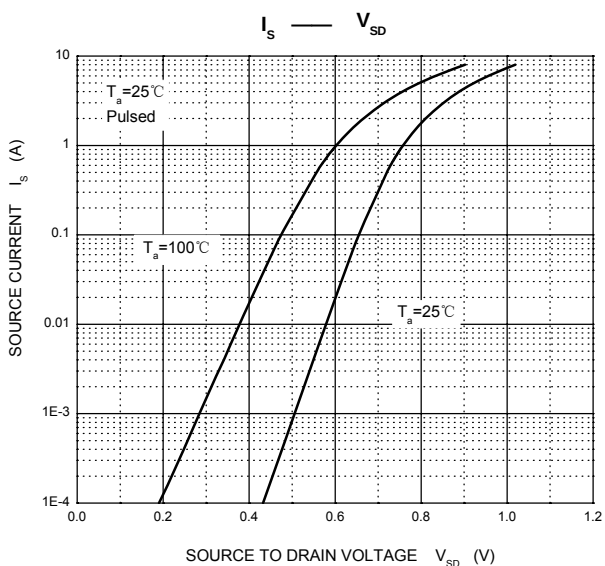
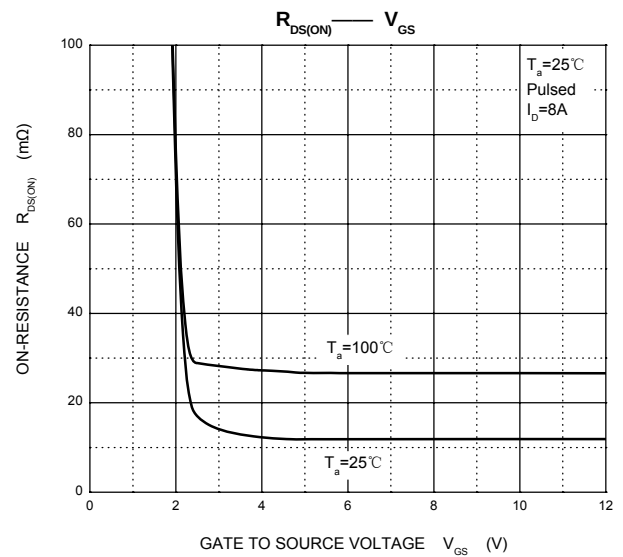
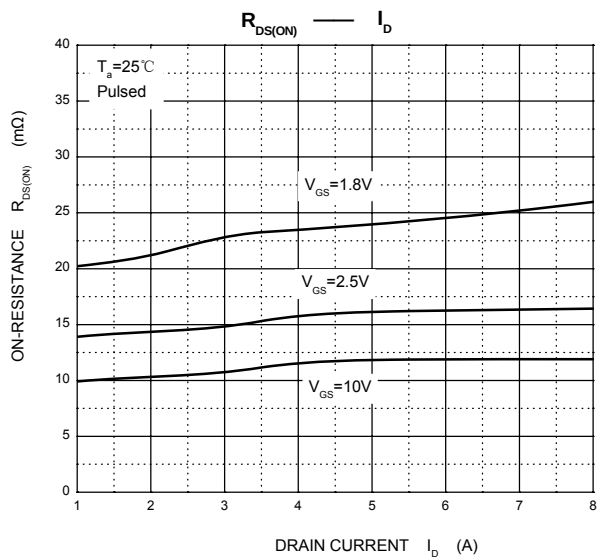
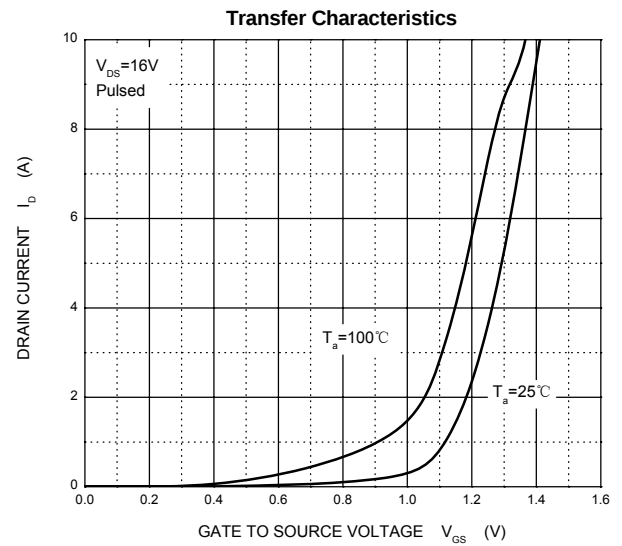
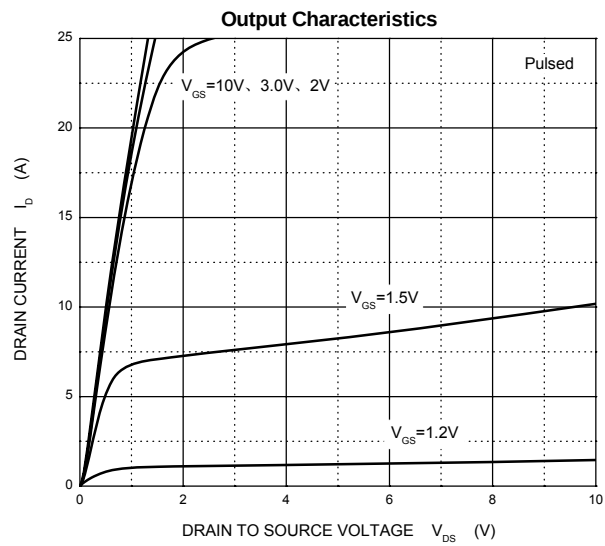
$T_a=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 16V, V_{GS} = 0V$			10	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$			± 10	μA
Gate threshold voltage (note 1)	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.5		1	V
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 8A$			13	m Ω
		$V_{GS} = 4.5V, I_D = 5A$			14	m Ω
		$V_{GS} = 3.8V, I_D = 5A$			15.5	m Ω
		$V_{GS} = 2.5V, I_D = 4A$			19	m Ω
		$V_{GS} = 1.8V, I_D = 3A$			27	m Ω
Forward tranconductance (note 1)	g_{FS}	$V_{DS} = 5V, I_D = 8A$		17		S
Diode forward voltage(note 1)	V_{SD}	$I_S = 1A, V_{GS} = 0V$			1	V
DYNAMIC PARAMETERS (note 2)						
Input Capacitance	C_{iss}	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$		1800		pF
Output Capacitance	C_{oss}			230		pF
Reverse Transfer Capacitance	C_{rss}			200		pF
Total gate charge	Q_g	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 8A$		17.9		nC
Gate-source charge	Q_{gs}			1.5		nC
Gate-drain charge	Q_{gd}			4.7		nC
SWITCHING PARAMETERS(note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 10V, V_{DD} = 10V,$ $R_L = 1.2\Omega, R_{GEN} = 3\Omega$		2.5		ns
Turn-on rise time	t_r			7.2		ns
Turn-off delay time	$t_{d(off)}$			49		ns
Turn-off fall time	t_f			10.8		ns

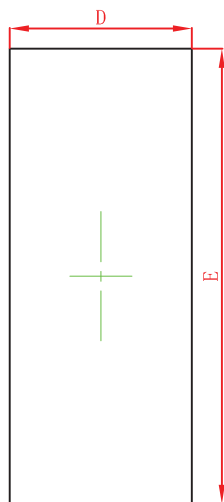
Notes :

1. Pulse Test : Pulse width $\leq 300\mu s$, duty cycle $\leq 0.5\%$.
2. Guaranteed by design, not subject to production testing.

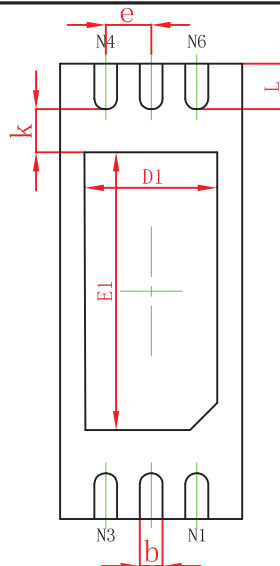
Typical Characteristics



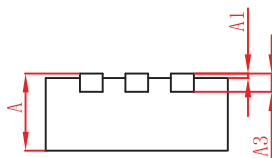
DFNWB5X2-6L-A Package Outline Dimensions



Top View



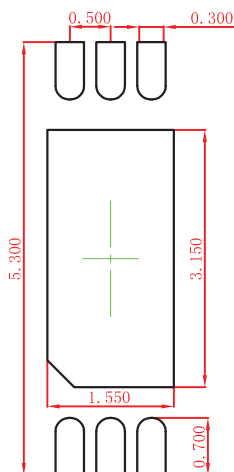
Bottom View



Side View

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.203REF.		0.008REF.	
D	1.924	2.076	0.076	0.082
E	4.924	5.076	0.194	0.200
D1	1.350	1.550	0.053	0.061
E1	2.950	3.150	0.116	0.124
k	0.200MIN.		0.008MIN.	
b	0.200	0.300	0.008	0.012
e	0.500TYP.		0.020TYP.	
L	0.424	0.576	0.017	0.023

DFNWB5X2-6L-A Suggested Pad Layout



Note:

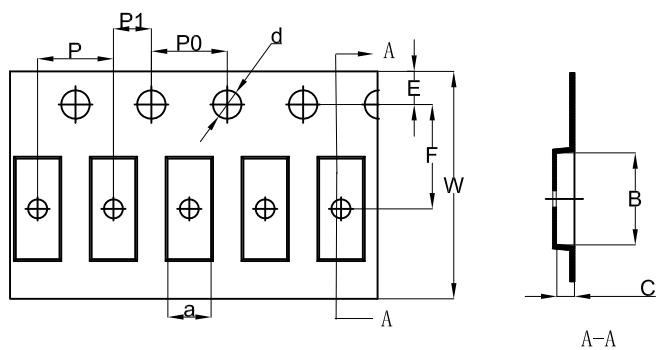
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.050\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

DFNWB5X2-6L Tape and Reel

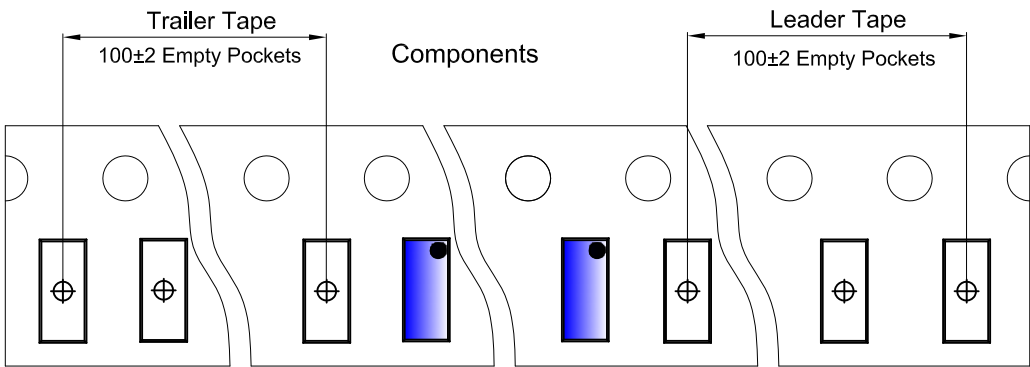
DFNWB5*2-6L Embossed Carrier Tape



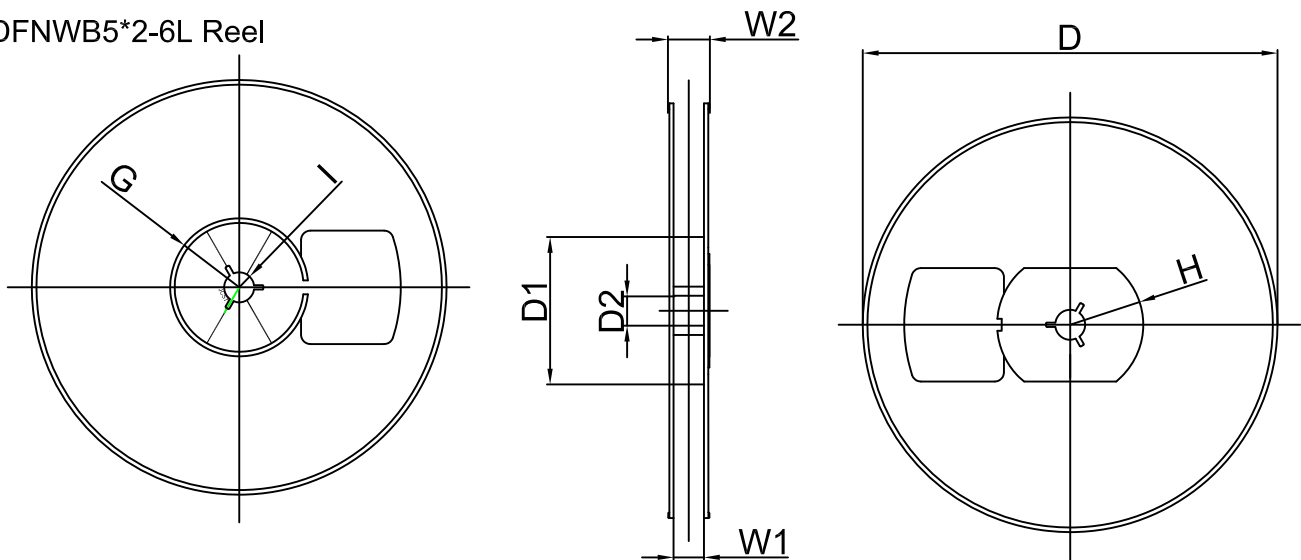
Packaging Description:
DFNWB5*2-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).
ALL DIM IN mm

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
DFNWB2×2-6L	2.30	5.30	1.05	Ø1.50	1.75	5.50	4.00	4.00	2.00	12.00

DFNWB5*2-6L Tape Leader and Trailer



DFNWB5*2-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R30.00	R32.00	R6.50	13.20	16.50

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
2500 pcs	7 inch	25,000 pcs	203×203×195	100,000 pcs	438×438×220	